

S-1170 Series

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HIGH RIPPLE-REJECTION AND LOW DROPOUT HIGH OUTPUT CURRENT CMOS VOLTAGE REGULATOR

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The S-1170 Series is a positive voltage regulator with a low dropout voltage, high-accuracy output voltage, and low current consumption developed based on CMOS technology.

A built-in low on-resistance transistor provides a low dropout voltage and large output current, a built-in overcurrent protection circuit prevents the load current from exceeding the current capacity of the output transistor, and a built-in thermal shutdown circuit prevents damage caused by the heat. An ON/OFF circuit ensures a long battery life. Compared with the voltage regulators using the conventional CMOS technology, a larger variety of capacitors are available, including small ceramic capacitors. Small SOT-89-5 and 6-Pin HSON(A) packages realize high-density mounting.

■ Features

• Output voltage: 1.5 V to 5.5 V, selectable in 0.1 V step

• Output voltage accuracy: ±1.0%

• Dropout voltage: 120 mV typ. (3.0 V output product, I_{OUT} = 300 mA)

• Current consumption: During operation: 80 μA typ., 160 μA max.

During power-off: 0.1 μA typ., 1.0 μA max.

• Output current: Possible to output 800 mA $(V_{IN} \ge V_{OUT(S)} + 1)$

Output current: Possible to output 800 mA (V_{IN} ≥ V_{OUT(S)} + 1.0 V)^{*1}
 Input and output capacitors: A ceramic capacitor of 4.7 μF or more can be used.

• Ripple rejection: 70 dB typ. (f = 1.0 kHz)

• Built-in overcurrent protection circuit: Limits overcurrent of output transistor.

• Built-in thermal shutdown circuit: Prevents damage caused by heat.

Built-in ON/OFF circuit: Ensures long battery life.
 Operation temperature range: Ta = -40°C to +85°C

• Lead-free, Sn 100%, halogen-free*2

*1. Attention should be paid to the power dissipation of the package when the output current is large.

*2. Refer to "■ Product Name Structure" for details.

■ Applications

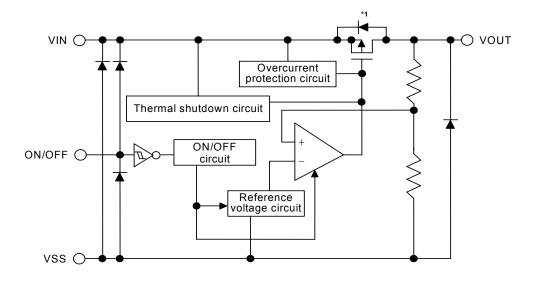
- Constant-voltage power supply for DVD and CD-ROM drive
- Constant-voltage power supply for battery-powered device
- Constant-voltage power supply for personal communication device
- Constant-voltage power supply for notebook PC

■ Packages

- SOT-89-5
- 6-Pin HSON(A)

1

■ Block Diagram



*1. Parasitic diode

Figure 1

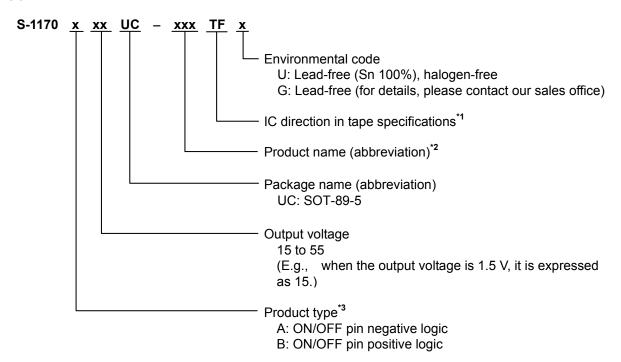
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■ Product Name Structure

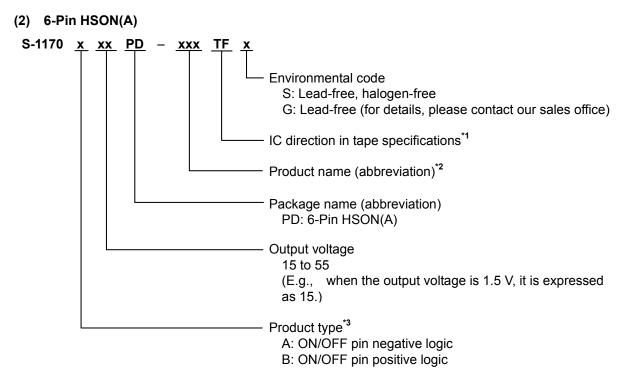
Users can select the product type, output voltage, and package type for the S-1170 Series. Refer to "1. **Product name**" regarding the contents of product name, "2. **Packages**" regarding the package drawings, "3. **Product name list**" regarding details of the product name.

1. Product name

(1) SOT-89-5



- *1. Refer to the tape drawing.
- *2. Refer to the product name list.
- *3. Refer to "3. ON/OFF pin" in "■ Operation".



- *1. Refer to the tape drawing.
- *2. Refer to the product name list.
- *3. Refer to "3. ON/OFF pin" in "■ Operation".

2. Packages

Dookaga Nama		Drawing Code		
Package Name	Package	Tape	į	Reel
SOT-89-5	UP005-A-P-SD	UP005-A-C-SD	i	UP005-A-R-SD
6-Pin HSON(A)	PD006-A-P-SD	PD006-A-C-SD	l I	PD006-A-R-SD

3. Product name list

Table 1

Output Voltage	SOT-89-5	6-Pin HSON(A)
1.5 V ±1.0%	S-1170B15UC-OTATFx	S-1170B15PD-OTATFz
1.6 V ±1.0%	S-1170B16UC-OTBTFx	S-1170B16PD-OTBTFz
1.7 V ±1.0%	S-1170B17UC-OTCTFx	S-1170B17PD-OTCTFz
1.8 V ±1.0%	S-1170B18UC-OTDTFx	S-1170B177 D-010172
1.9 V ±1.0%	S-1170B19UC-OTETFX	S-1170B19PD-OTETFz
2.0 V ±1.0%	S-1170B20UC-OTFTFx	S-1170B20PD-OTFTFz
2.1 V ±1.0%	S-1170B21UC-OTGTFx	S-1170B20FD-OTFTZ
2.1 V ±1.0% 2.2 V ±1.0%	S-1170B22UC-OTHTFX	S-1170B211 D-010112
2.3 V ±1.0%	S-1170B23UC-OTITFX	S-1170B22FD-OTITFZ
2.4 V ±1.0%	S-1170B230C-OTITTX	S-1170B24PD-OTJTFz
2.5 V ±1.0%	S-1170B25UC-OTKTFx	S-1170B25FD-OTKTFz
2.6 V ±1.0%	S-1170B26UC-OTLTFx	S-1170B25FD-OTKTFZ
2.7 V ±1.0%	S-1170B27UC-OTMTFX	S-1170B20FD-OTLTF2
2.8 V ±1.0%	S-1170B28UC-OTNTFX	S-1170B27FD-OTMTFZ
2.9 V ±1.0%	S-1170B280C-OTNTFX	S-1170B29PD-OTOTFz
	S-1170B30UC-OTPTFx	S-1170B30PD-OTPTFz
3.0 V ±1.0%		
3.1 V ±1.0%	S-1170B31UC-OTQTFx	S-1170B31PD-OTQTFz
3.2 V ±1.0%	S-1170B32UC-OTRTFx	S-1170B32PD-OTRTFz
3.3 V ±1.0%	S-1170B33UC-OTSTFx	S-1170B33PD-OTSTFz
3.4 V ±1.0%	S-1170B34UC-OTTTFx	S-1170B34PD-OTTTFz
3.5 V ±1.0%	S-1170B35UC-OTUTFx	S-1170B35PD-OTUTFz
3.6 V ±1.0%	S-1170B36UC-OTVTFx	S-1170B36PD-OTVTFz
3.7 V ±1.0%	S-1170B37UC-OTWTFx	S-1170B37PD-OTWTFz
3.8 V ±1.0%	S-1170B38UC-OTXTFx	S-1170B38PD-OTXTFz
3.9 V ±1.0%	S-1170B39UC-OTYTFx	S-1170B39PD-OTYTFz
4.0 V ±1.0%	S-1170B40UC-OTZTFx	S-1170B40PD-OTZTFz
4.1 V ±1.0%	S-1170B41UC-OUATFx	S-1170B41PD-OUATFz
4.2 V ±1.0%	S-1170B42UC-OUBTFx	S-1170B42PD-OUBTFz
4.3 V ±1.0%	S-1170B43UC-OUCTFx	S-1170B43PD-OUCTFz
4.4 V ±1.0%	S-1170B44UC-OUDTFx	S-1170B44PD-OUDTFz
4.5 V ±1.0%	S-1170B45UC-OUETFx	S-1170B45PD-OUETFz
4.6 V ±1.0%	S-1170B46UC-OUFTFx	S-1170B46PD-OUFTFz
4.7 V ±1.0%	S-1170B47UC-OUGTFx	S-1170B47PD-OUGTFz
4.8 V ±1.0%	S-1170B48UC-OUHTFx	S-1170B48PD-OUHTFz
4.9 V ±1.0%	S-1170B49UC-OUITFx	S-1170B49PD-OUITFz
5.0 V ±1.0%	S-1170B50UC-OUJTFx	S-1170B50PD-OUJTFz
5.1 V ±1.0%	S-1170B51UC-OUKTFx	S-1170B51PD-OUKTFz
5.2 V ±1.0%	S-1170B52UC-OULTFx	S-1170B52PD-OULTFz
5.3 V ±1.0%	S-1170B53UC-OUMTFx	S-1170B53PD-OUMTFz
5.4 V ±1.0%	S-1170B54UC-OUNTFx	S-1170B54PD-OUNTFz
5.5 V ±1.0%	S-1170B55UC-OUOTFx	S-1170B55PD-OUOTFz

Remark 1. Please contact our sales office for products with an output voltage other than those specified above or type A products.

- 2. x: G or U z: G or S
- **3.** Please select products of environmental code = U for Sn 100%, halogen-free products.

■ Pin Configurations

SOT-89-5 Top view

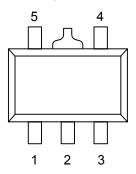


Figure 2

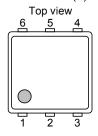
Table 2

Pin No.	Symbol	Description
1	ON/OFF	ON/OFF pin
2	VSS	GND pin
3	NC ^{*1}	No connection
4	VIN	Input voltage pin
5	VOUT	Output voltage pin

*1. The NC pin is electrically open.

The NC pin can be connected to VIN pin or VSS pin.

6-Pin HSON(A)



- *1. Connect the exposed thermal die pad at shadowed area to the board, and set electric potential open or VSS.
 - However, do not use it as the function of electrode.
- *2. Be careful of the contact with other wires because the pinch lead has the same electric potential as VSS.

Figure 3

Table 3

Pin No.	Symbol	Description
1	VOUT*1	Output voltage pin
2	VOUT*1	Output voltage pin
3	ON/OFF	ON/OFF pin
4	VSS	GND pin
5	VIN ^{*2}	Input voltage pin
6	VIN*2	Input voltage pin

- *1. Short pins 1 and 2.
- *2. Short pins 5 and 6.

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■ Absolute Maximum Ratings

Table 4

 $(Ta = 25^{\circ}C \text{ unless otherwise specified})$

Parameter		Symbol	Absolute Maximum Rating	Unit
lanut valtage		V _{IN}	V_{SS} – 0.3 to V_{SS} + 7	V
input voitage	Input voltage		V_{SS} – 0.3 to V_{IN} + 0.3	V
Output voltage		V_{OUT}	$V_{SS} - 0.3$ to $V_{IN} + 0.3$	V
Power	SOT-89-5	D	1000 *1	mW
dissipation	6-Pin HSON(A)	P_{D}	1000	IIIVV
Operation ambient temperature		T_{opr}	−40 to +85	°C
Storage temperature		T_{stg}	−40 to +125	°C

*1. At mounted on printed circuit board

[Mounted board]

(1) Board size: 40 mm × 40 mm × t1.6 mm(2) Cu wiring shear: 180 % at both sides

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

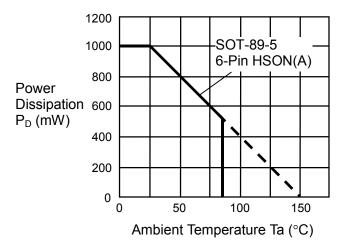


Figure 4 Power Dissipation of Package (Mounted on Printed Circuit Board)

Caution Thermal shutdown circuit may operate when junction temperature is 150 °C.

■ Electrical Characteristics

Table 5

 $(Ta = 25^{\circ}C \text{ unless otherwise specified})$ Test Conditions Parameter Symbol Min. Max. Unit Тур. Circuit $V_{OUT(S)}$ $V_{OUT(S)}$ $V_{OUT(S)}$ Output voltage*1 ٧ $V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, I_{OUT} = 100 \text{ mA}$ 1 $V_{OUT(E)}$ × 0.99 × 1.01 Output current*2 800^{*5} $V_{IN} \ge V_{OUT(S)} + 1.0 \text{ V}$ 3 mΑ I_{OUT} 0.45 $V_{OUT(S)} = 1.5 \text{ V}$ 0.35 V 1 ٧ 1 $V_{OUT(S)} = 1.6 \text{ V}$ 0.30 0.35 $V_{OUT(S)} = 1.7 \text{ V}$ V 0.25 0.30 1 Dropout voltage*3 V_{drop} $I_{OUT} = 300 \text{ mA}$ $1.8~V \leq V_{OUT(S)} \leq 2.0~V$ 0.20 0.26 V 1 $2.1~V \leq V_{OUT(S)} \leq 2.9~V$ V 1 0.15 0.22 $3.0 \text{ V} \leq V_{OUT(S)} \leq 5.5 \text{ V}$ 0.12 0.18 V 1 ΔV_{OUT1} $V_{OUT(S)} + 0.5 \text{ V} \le V_{IN} \le 6.5 \text{ V},$ Line regulation 0.05 0.3 %/V 1 $I_{OUT} = 100 \text{ mA}$ $\Delta V_{IN} \bullet V_{OUT}$ $V_{IN} = V_{OUT(S)} + 1.0 V,$ 1 Load regulation ΔV_{OUT2} 30 100 mV $1.0~mA \leq I_{OUT} \leq 300~mA$ $V_{IN}\!=V_{OUT(S)}\!+1.0~V,~I_{OUT}=10~mA,$ Output voltage ΔV_{OUT} ppm ±150 1 temperature coefficient*4 –40°C ≤ Ta ≤ 85°C / °C ∆Ta•V_{OUT} $V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, \text{ ON/OFF pin} = \text{ON},$ Current consumption I_{SS1} 80 160 μΑ 2 during operation no load Current consumption $V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, \text{ ON/OFF pin} = \text{OFF},$ Iss2 0.1 1.0 μΑ 2 during power-off no load Input voltage V_{IN} 2.0 6.5 V ON/OFF pin $V_{\text{SH}} \\$ $V_{IN}\!=V_{OUT(S)}\!+1.0~V,~R_L\!=1.0~k\Omega$ 1.5 ٧ 4 input voltage "H" ON/OFF pin V_{SL} $V_{IN}\!=V_{OUT(S)}\!+1.0~V,~R_L\!=1.0~k\Omega$ 0.3 ٧ 4 input voltage "L" ON/OFF pin $V_{IN} = 6.5 \text{ V}, V_{ON/OFF} = 6.5 \text{ V}$ -0.10.1 μА 4 I_{SH} input current "H" ON/OFF pin $V_{IN} = 6.5 \text{ V}, V_{ON/OFF} = 0 \text{ V}$ -0.10.1 μА 4 I_{SL} input current "L" $V_{IN} = V_{OUT(S)} + 1.0 V,$ $1.5~V \leq V_{OUT(S)} \leq 3.0~V$ 5 70 dB f = 1.0 kHz,RR Ripple rejection $\Delta V_{rin} = 0.5 \text{ Vrms},$ $3.1~V \leq V_{OUT(S)} \leq 5.5~V$ 65 dΒ 5 $I_{OUT} = 100 \text{ mA}$ $V_{IN} = V_{OUT(S)} + 1.0 V$, ON/OFF pin = ON, Short-circuit current 350 mΑ 3 I_{short} $V_{OUT} = 0 V$ Thermal shutdown Junction temperature 150 ٥С T_{SD} detection temperature Thermal shutdown 120 °С T_{SR} Junction temperature release temperature

HIGH RIPPLE-REJECTION LOW DROPOUT HIGH OUTPUT CURRENT CMOS VOLTAGE REGULATOR Rev.4.1_02 S-1170 Series

*1. V_{OUT(S)}: Set output voltage

V_{OUT(E)}: Actual output voltage

Output voltage when fixing I_{OUT} (= 100 mA) and inputting $V_{OUT(S)} + 1.0 \text{ V}$

- *2. The output current at which the output voltage becomes 95% of V_{OUT(E)} after gradually increasing the output current.
- *3. $V_{drop} = V_{IN1} (V_{OUT3} \times 0.98)$

 V_{OUT3} is the output voltage when $V_{IN} = V_{OUT(S)} + 1.0 \text{ V}$ and $I_{OUT} = 300 \text{ mA}$.

 V_{IN1} is the input voltage at which the output voltage becomes 98% of V_{OUT3} after gradually decreasing the input voltage.

*4. A change in the temperature of the output voltage [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{OUT}}{\Delta Ta} \left[\text{mV/°C} \right]^{*1} = V_{OUT(S)} \left[V \right]^{*2} \times \frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}} \left[\text{ppm/°C} \right]^{*3} \div 1000$$

- *1. Change in temperature of output voltage
- *2. Set output voltage
- *3. Output voltage temperature coefficient
- *5. The output current can be at least this value.

Due to restrictions on the package power dissipation, this value may not be satisfied. Attention should be paid to the power dissipation of the package when the output current is large.

This specification is guaranteed by design.

■ Test Circuits

1.

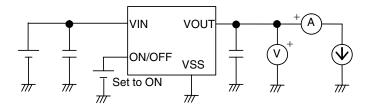


Figure 5

2.

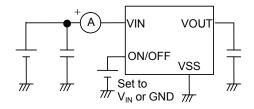


Figure 6

3.

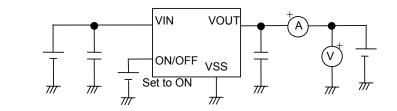


Figure 7

4.

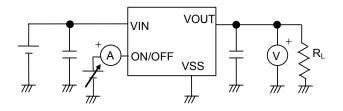


Figure 8

5.

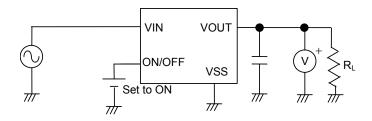
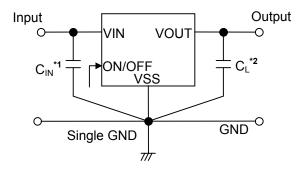


Figure 9

■ Standard Circuit



- *1. C_{IN} is a capacitor for stabilizing the input.
- *2. A ceramic capacitor of 4.7 μ F or more can be used for C₁.

Figure 10

Caution The above connection diagram and constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.

■ Condition of Application

Input capacitor (C_{IN}): 4.7 μF or more Output capacitor (C_L): 4.7 μF or more ESR of output capacitor: 0.5 Ω or less

Caution Generally a series regulator may cause oscillation, depending on the selection of external parts. Check that no oscillation occurs with the application using the above capacitor.

■ Selection of Input and Output Capacitors (C_{IN}, C_L)

The S-1170 Series requires an output capacitor between the VOUT pin and the VSS pin for phase compensation. A ceramic capacitor with a capacitance of 4.7 μF or more provides a stable operation in all temperature ranges. When using an OS capacitor, a tantalum capacitor, or an aluminum electrolytic capacitor, the capacitance must be 4.7 μF or more, and the ESR must be 0.5 Ω or less.

The output overshoot and undershoot values, which are transient response characteristics, vary depending on the output capacitor value. The required capacitance value for the input capacitor differs depending on the application.

The recommended value for an application is $C_{IN} \ge 4.7~\mu F$ and $C_L \ge 4.7~\mu F$, however, perform a thorough evaluation using the actual device, including evaluation of temperature characteristics.

■ Explanation of Terms

1. Low dropout voltage regulator

This voltage regulator has the low dropout voltage due to its built-in low on-resistance transistor.

2. Low ESR

A capacitor whose ESR (Equivalent Series Resistance) is low. The S-1170 Series enables use of a low ESR capacitor, such as a ceramic capacitor, for the output-side capacitor (C_L). A capacitor whose ESR is 0.5 Ω or less can be used.

3. Output voltage (Vout)

The accuracy of the output voltage is ensured at $\pm 1.0\%$ under the specified conditions of fixed input voltage^{*1}, fixed output current, and fixed temperature.

*1. Differs depending the product.

Caution If the above conditions change, the output voltage value may vary and exceed the accuracy range of the output voltage. Refer to "■ Electrical Characteristics" and "■ Characteristics (Typical Data)" for details.

4. Line regulation
$$\left(\frac{\Delta V_{\text{OUT1}}}{\Delta V_{\text{IN}} \bullet V_{\text{OUT}}}\right)$$

Indicates the dependency of the output voltage on the input voltage. That is, the values show how much the output voltage changes due to a change in the input voltage with the output current remaining unchanged.

5. Load regulation (ΔV_{OUT2})

Indicates the dependency of the output voltage on the output current. That is, the values show how much the output voltage changes due to a change in the output current with the input voltage remaining unchanged.

6. Dropout voltage (V_{drop})

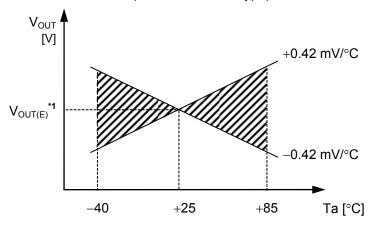
Indicates the difference between input voltage (V_{IN1}) and the output voltage when; decreasing input voltage (V_{IN}) gradually until the output voltage has dropped out to the value of 98% of output voltage (V_{OUT3}), which is at $V_{IN} = V_{OUT(S)} + 1.0 \text{ V}$.

$$V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$$

7. Output voltage temperature coefficient $\left(\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}\right)$

The shaded area in **Figure 11** is the range where V_{OUT} varies in the operation temperature range when the output voltage temperature coefficient is ± 150 ppm/°C.

Example of S-1170B28 typ. product



*1. $V_{OUT(E)}$ is the value of the output voltage measured at Ta = +25°C.

Figure 11

A change in the temperature of the output voltage [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{OUT}}{\Delta Ta} \left[mV/^{\circ}C \right]^{*1} = V_{OUT(S)} \left[V \right]^{*2} \times \frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}} \left[ppm/^{\circ}C \right]^{*3} \div 1000$$

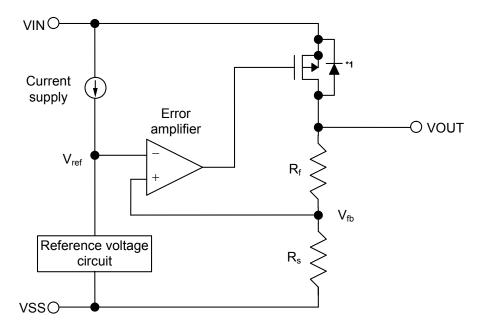
- *1. Change in temperature of output voltage
- *2. Set output voltage
- *3. Output voltage temperature coefficient

Operation

1. Basic operation

Figure 12 shows the block diagram of the S-1170 Series.

The error amplifier compares the reference voltage (V_{ref}) with feedback voltage (V_{fb}), which is the output voltage resistance-divided by feedback resistors (R_s and R_f). It supplies the gate voltage necessary to maintain the constant output voltage which is not influenced by the input voltage and temperature change, to the output transistor.



*1. Parasitic diode

Figure 12

2. Output transistor

In the S-1170 Series, a low on-resistance P-channel MOS FET is used as the output transistor. Be sure that V_{OUT} does not exceed $V_{\text{IN}} + 0.3$ V to prevent the voltage regulator from being damaged due to reverse current flowing from the VOUT pin through a parasitic diode to the VIN pin, when the potential of V_{OUT} became higher than V_{IN} .

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3. ON/OFF pin

This pin starts and stops the regulator.

When the ON/OFF pin is set to OFF level, the entire internal circuit stops operating, and the built-in P-channel MOS FET output transistor between the VIN pin and the VOUT pin is turned off, reducing current consumption significantly. The VOUT pin becomes the V_{SS} level due to the internally divided resistance of several hundreds $k\Omega$ between the VOUT pin and the VSS pin.

The structure of the ON/OFF pin is as shown in **Figure 13**. Since the ON/OFF pin is neither pulled down nor pulled up internally, do not use it in the floating status. In addition, note that the current consumption increases if a voltage of 0.3 V to $\text{V}_{\text{IN}} - 0.3 \text{ V}$ is applied to the ON/OFF pin. When not using the ON/OFF pin, connect it to the VSS pin in the product A type, and connect it to the VIN pin in B type.

Table 6

Product Type	ON/OFF Pin	Internal Circuit	VOUT Pin Voltage	Current Consumption
А	"L": ON	Operate	Set value	I _{SS1}
А	"H": OFF	Stop	V _{SS} level	I _{SS2}
В	"L": OFF	Stop	V _{SS} level	I _{SS2}
В	"H": ON	Operate	Set value	I _{SS1}

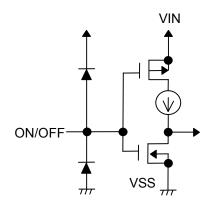


Figure 13

4. Thermal shutdown circuit

The S-1170 Series implements a thermal shutdown circuit to protect the device from damage due to overheating. When the junction temperature rises to 150°C (typ.), the thermal shutdown circuit operates and the regulator operation stops. When the junction temperature drops to 120°C (typ.), the thermal shutdown circuit is released and the regulator operation resumes.

If the thermal shutdown circuit starts operating due to self-heating, the regulator operation stops and the output voltage falls. When the regulator operation has stopped, no self-heat is generated and the temperature of the IC is lowered. When the temperature has dropped, the thermal shutdown circuit is released, the regulator operation resumes, and self-heat is generated again. By repeating this procedure, the output voltage waveform forms pulses. Stop or restart of regulation continues unless decreasing either or both of the input voltage and the output current in order to reduce the internal power consumption, or decreasing the ambient temperature.

Table 7

Thermal Shutdown Circuit	VOUT Pin Voltage
Operating: 150°C (typ.)	V _{ss} level
Released: 120°C (typ.)	Set value

■ Precautions

- Wiring patterns for the VIN pin, the VOUT pin and GND should be designed so that the impedance is low. When mounting an output capacitor between the VOUT pin and the VSS pin (C_L) and a capacitor for stabilizing the input between the VIN pin and the VSS pin (C_{IN}), the distance from the capacitors to these pins should be as short as possible.
- Note that generally the output voltage may increase when a series regulator is used at low load current (1.0 mA or less).
- Note that the output voltage may increase due to the leakage current from an output driver even if the ON/OFF pin is at OFF level when a series regulator is used at high temperature.
- Generally a series regulator may cause oscillation, depending on the selection of external parts. The
 following conditions are recommended for the S-1170 Series. However, be sure to perform sufficient
 evaluation under the actual usage conditions for selection, including evaluation of temperature
 characteristics.

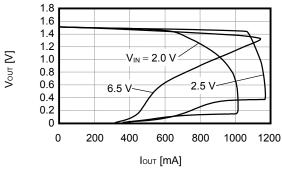
Input capacitor (C_{IN}): 4.7 μF or more Output capacitor (C_{L}): 4.7 μF or more Equivalent series resistance (ESR): 0.5 Ω or less

- The voltage regulator may oscillate when the impedance of the power supply is high and the input capacitance is small or an input capacitor is not connected.
- Overshoot may occur in the output voltage momentarily if the voltage is rapidly raised at power-on or when the power supply fluctuates. Sufficiently evaluate the output voltage at power-on with the actual device.
- The application conditions for the input voltage, the output voltage, and the load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- In determining the output current, attention should be paid to the output current value specified in Table
 5 in "■ Electrical Characteristics" and footnote *5 of the table.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

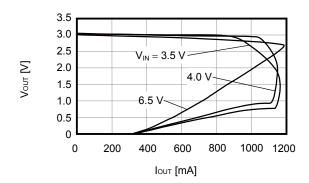
■ Characteristics (Typical Data)

(1) Output voltage vs. Output current (when load current increases)

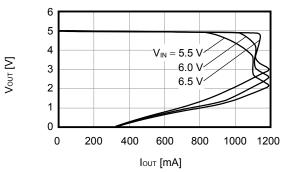
S-1170B15 (Ta = 25°C)



S-1170B30 (Ta = 25°C)



S-1170B50 (Ta = 25°C)

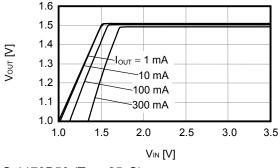


Remark In determining the output current, attention should be paid to the following.

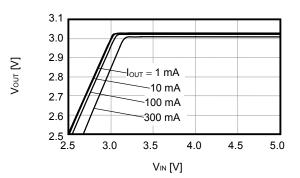
- The minimum output current value and footnote *5 in Table 5 in "■ Electrical Characteristics"
- 2. The package power dissipation

(2) Output voltage vs. Input voltage

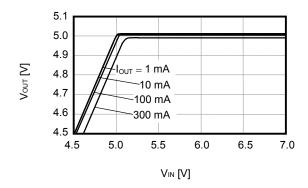
S-1170B15 ($Ta = 25^{\circ}C$)



S-1170B30 (Ta = 25°C)

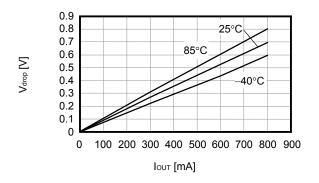


S-1170B50 (Ta = 25°C)

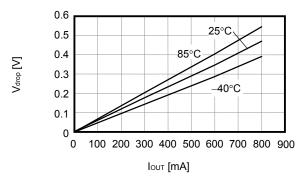


(3) Dropout voltage vs. Output current

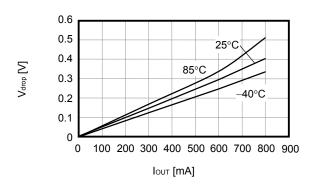
S-1170B15



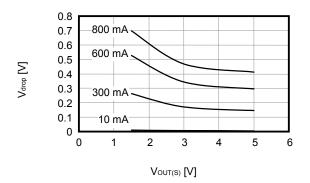
S-1170B30



S-1170B50

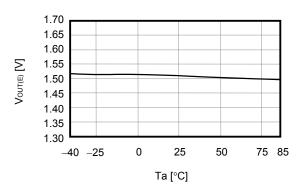


(4) Dropout voltage vs. Set output voltage

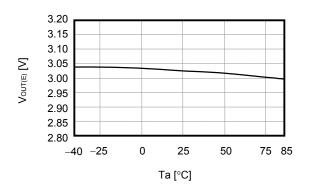


(5) Output voltage vs. Ambient temperature

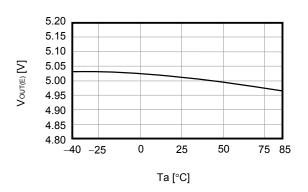
 $S-1170B15 (I_{OUT} = 10 mA)$



 $S-1170B30 (I_{OUT} = 10 \text{ mA})$

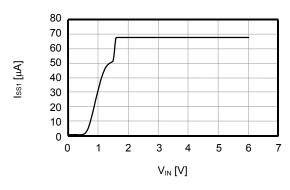


 $S-1170B50 (I_{OUT} = 10 \text{ mA})$

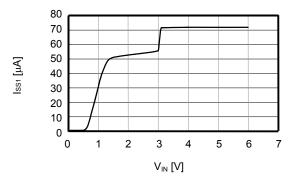


(6) Current consumption vs. Input voltage

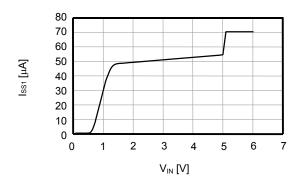
S-1170B15 (Ta = 25°C)



S-1170B30 (Ta = 25°C)



S-1170B50 (Ta = 25°C)

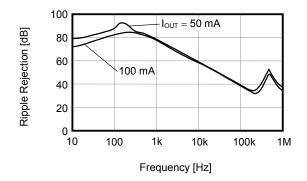


HIGH RIPPLE-REJECTION LOW DROPOUT HIGH OUTPUT CURRENT CMOS VOLTAGE REGULATOR Rev.4.1_02 S-1170 Series

(7) Ripple rejection

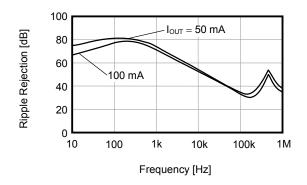
S-1170B15 ($Ta = 25^{\circ}C$)

 $V_{\text{IN}} = 2.5 \; V, \; C_{\text{OUT}} = 4.7 \; \mu F$



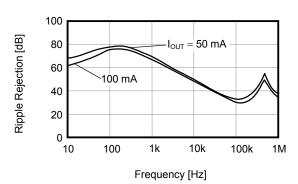
S-1170B30 (Ta = 25°C)

 $V_{\text{IN}} = 4.0 \ \text{V}, \ C_{\text{OUT}} = 4.7 \ \mu F$



S-1170B50 (Ta = 25°C)

 $V_{\text{IN}} = 6.0 \ \text{V, Cout} = 4.7 \ \mu \text{F}$

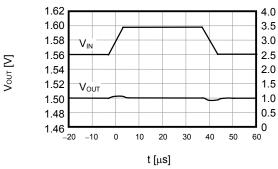


■ Reference Data

(1) Input transient response characteristics

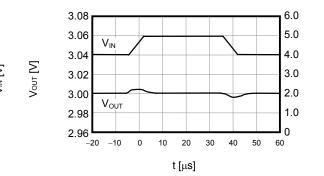
S-1170B15

lout = 100 mA, $t_r = t_f = 5.0~\mu\text{s},~C\text{out} = 4.7~\mu\text{F},~C\text{in} = 4.7~\mu\text{F}$



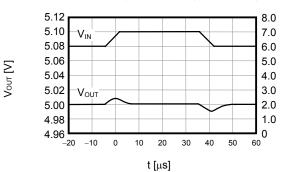
S-1170B30

lout = 100 mA, $t_{r}=t_{f}=5.0~\mu s,~Cout=4.7~\mu F,~C_{IN}=4.7~\mu F$



S-1170B50

lout = 100 mA, $t_r = t_f$ = 5.0 μ s, Cout = 4.7 μ F, Cin = 4.7 μ F

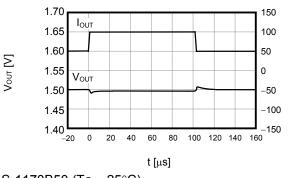


∑ | |

(2) Load transient response characteristics

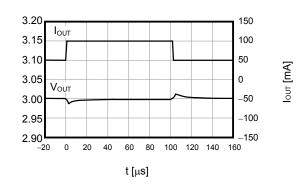
S-1170B15 (Ta = 25°C)

 $V_{IN} = 2.5 \text{ V}$, $C_{OUT} = 4.7 \text{ }\mu\text{F}$, $C_{IN} = 4.7 \text{ }\mu\text{F}$, $I_{OUT} = 50 \text{ mA} \leftrightarrow 100 \text{ mA}$



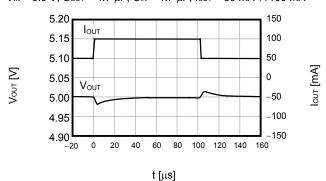
S-1170B30 (Ta = 25° C)

 $V_{IN} = 4.0 \text{ V}$, $C_{OUT} = 4.7 \text{ }\mu\text{F}$, $C_{IN} = 4.7 \text{ }\mu\text{F}$, $I_{OUT} = 50 \text{ mA} \leftrightarrow 100 \text{ mA}$



S-1170B50 (Ta = 25°C)

 $V_{IN} = 6.0 \text{ V}$, $C_{OUT} = 4.7 \text{ }\mu\text{F}$, $C_{IN} = 4.7 \text{ }\mu\text{F}$, $I_{OUT} = 50 \text{ }mA \leftrightarrow 100 \text{ }mA$

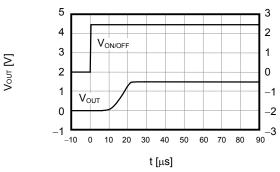


Vouт [V]

(3) ON/OFF pin transient response characteristics

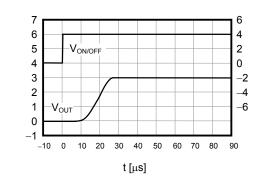
S-1170B15 (Ta = 25° C)

 $V_{\text{IN}} = 2.5 \ \text{V}, \ \text{Cout} = 4.7 \ \mu\text{F}, \ \text{C}_{\text{IN}} = 4.7 \ \mu\text{F}, \ \text{Iout} = 100 \ mA$



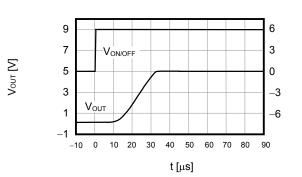
S-1170B30 (Ta = 25° C)

 $V_{\text{IN}} = 4.0 \ V, \ C_{\text{OUT}} = 4.7 \ \mu F, \ C_{\text{IN}} = 4.7 \ \mu F, \ I_{\text{OUT}} = 100 \ mA$



S-1170B50 (Ta = 25°C)

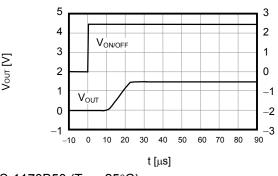
 $V_{IN} = 6.0 \ V$, $C_{OUT} = 4.7 \ \mu F$, $C_{IN} = 4.7 \ \mu F$, $I_{OUT} = 100 \ mA$



Von/OFF [V]

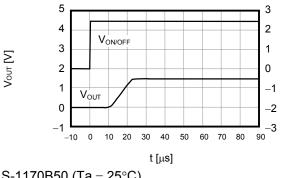
S-1170B15 ($Ta = 25^{\circ}C$)

 $V_{\text{IN}} = 2.5 \text{ V}, \, C_{\text{OUT}} = 4.7 \,\, \mu\text{F}, \, C_{\text{IN}} = 4.7 \,\, \mu\text{F}, \, I_{\text{OUT}} = 300 \,\, mA$

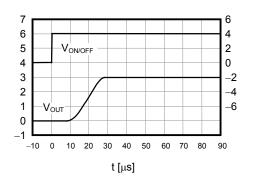


S-1170B30 (Ta = 25° C)

 $V_{\text{IN}} = 4.0 \text{ V}, \; C_{\text{OUT}} = 4.7 \; \mu\text{F}, \; C_{\text{IN}} = 4.7 \; \mu\text{F}, \; I_{\text{OUT}} = 300 \; mA$

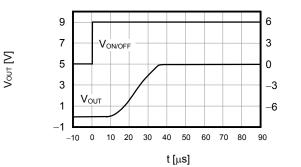




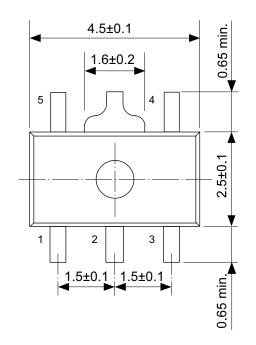


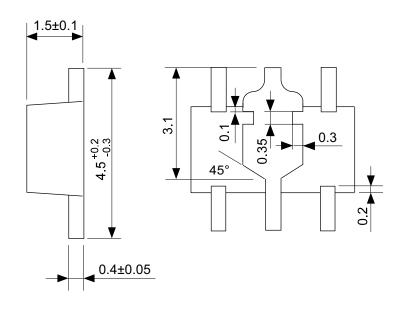
S-1170B50 (Ta = 25° C)

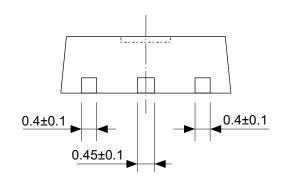
 $V_{\text{IN}} = 6.0 \ \text{V}, \ \text{Cout} = 4.7 \ \mu\text{F}, \ \text{C}_{\text{IN}} = 4.7 \ \mu\text{F}, \ \text{Iout} = 300 \ \text{mA}$



Von/off [V]

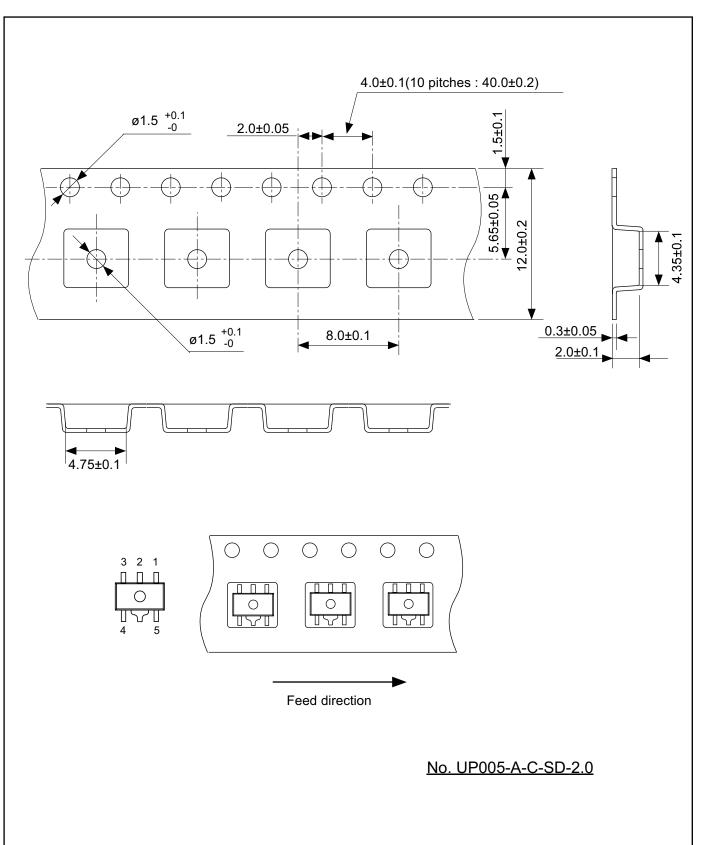




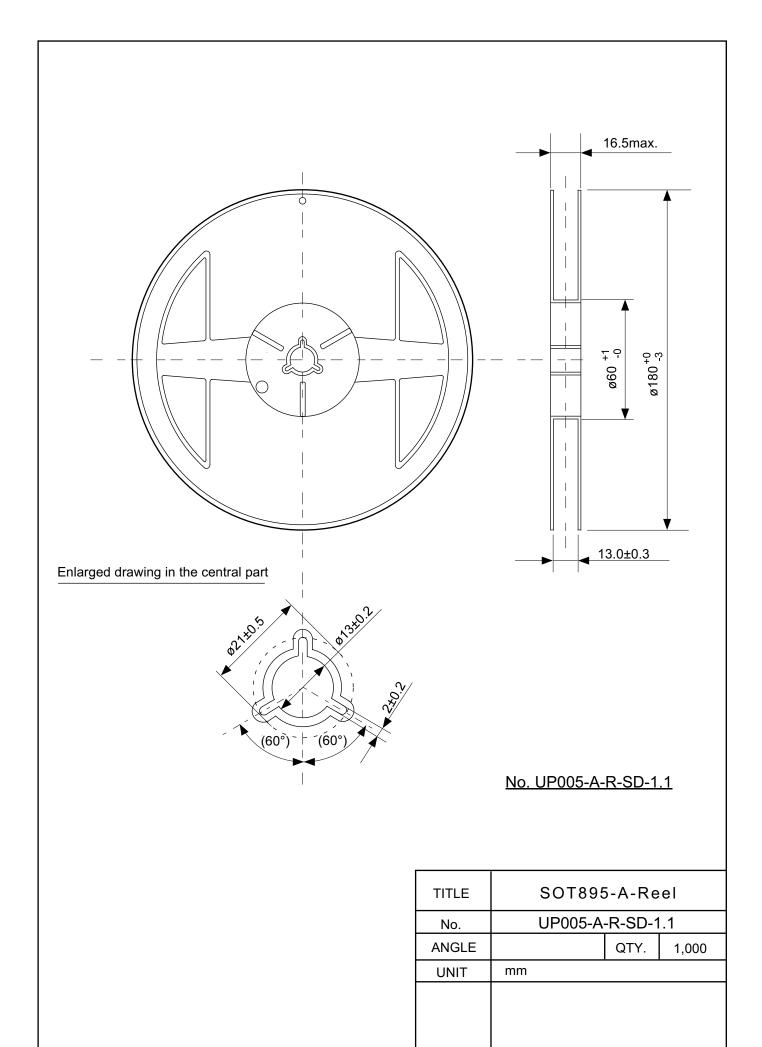


No. UP005-A-P-SD-2.0

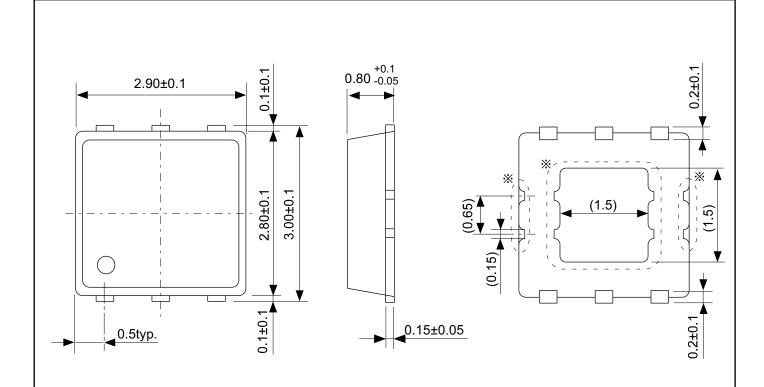
TITLE	SOT895-A-PKG Dimensions	
No.	UP005-A-P-SD-2.0	
ANGLE	Φ	
UNIT	mm	
ABLIC Inc.		

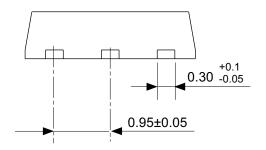


TITLE	SOT895-A-Carrier Tape		
No.	UP005-A-C-SD-2.0		
ANGLE			
UNIT	mm		
ABLIC Inc.			



ABLIC Inc.

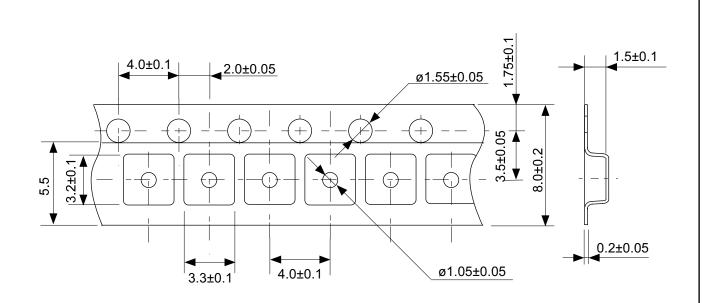


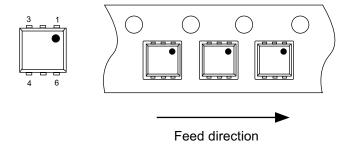


X The exposed thermal die pad has different electric potential depending on the product. Confirm specifications of each product. Do not use it as the function of electrode.

No. PD006-A-P-SD-5.0

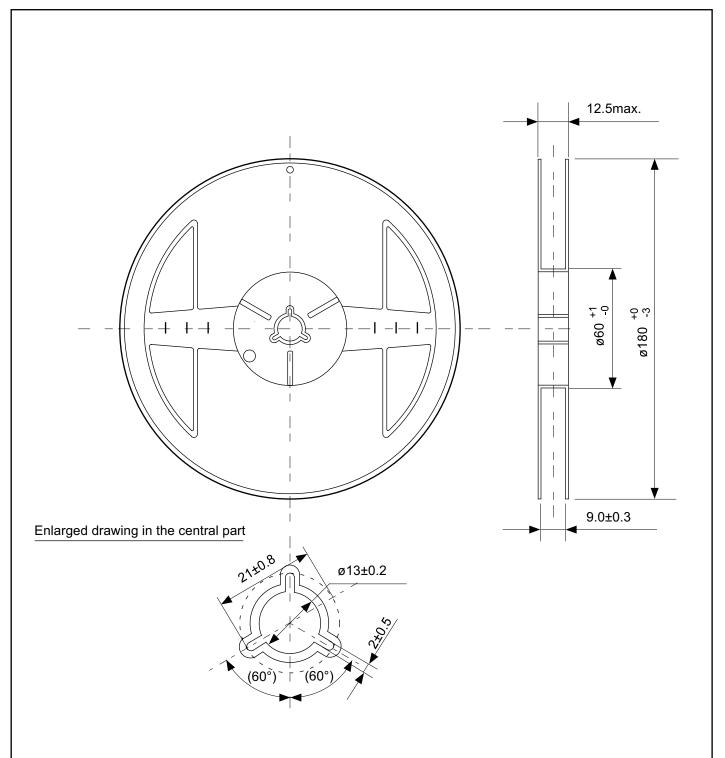
TITLE	HSON6A-A-PKG Dimensions	
No.	PD006-A-P-SD-5.0	
ANGLE	\$ E3	
UNIT	mm	
ABLIC Inc.		





No. PD006-A-C-SD-2.0

TITLE	HSON6A-A-Carrier Tape		
No.	PD006-A-C-SD-2.0		
ANGLE			
UNIT	mm		
ABLIC Inc.			



No. PD006-A-R-SD-1.0

TITLE	HSON6A-A-Reel		
No.	PD00	6-A-R-SD-	1.0
ANGLE	QTY. 3,000		
UNIT	mm		
ABLIC Inc.			

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